查询TL3472供应商

捷多邦,专业PCB打样工厂,24小时加急出货 TL3472 HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIER

10UT

V_{CC}_/GND

1IN-

1IN+ 3

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V_{CC+}

20UT

2IN+

6 2IN-

5 **П**

7

D OR P PACKAGE (TOP VIEW)

- Wide Gain-Bandwidth Product . . . 4 MHz
- High Slew Rate ... 13 V/μs
- Fast Settling Time . . . 1.1 μs to 0.1%
- Wide-Range Single-Supply Operation . . . 4 V to 36 V
- Wide Input Common-Mode Range Includes Ground (V_{CC}_)
- Low Total Harmonic Distortion ... 0.02%
- Large-Capacitance Drive Capability ... 10,000 pF
- Output Short-Circuit Protection

description

Quality, low-cost, bipolar fabrication with innovative design concepts are employed for the TL3472 operational amplifier. This device offers 4 MHz of gain-bandwidth product, 13-V/µs slew rate, and fast settling time, without the use of JFET device technology. Although the TL3472 can be operated from split supplies, it is particularly suited for single-supply operation because the common-mode input voltage range includes ground potential (V_{CC-}). With a Darlington transistor input stage, this device exhibits high input resistance, low input offset voltage, and high gain. The all-npn output stage, characterized by no dead-band crossover distortion and large output voltage swing, provides high-capacitance drive capability, excellent phase and gain margins, low open-loop high-frequency output impedance, and symmetrical source/sink ac frequency response. This low-cost amplifier is an alternative to the MC33072 and the MC34072 operational amplifiers.

The TL3472C is characterized for operation from 0°C to 70°C. The TL3472I is characterized for operation from –40°C to 105°C.

AVAILABLE OF HONS						
	PACKAG	PACKAGED DEVICES				
TA	SMALL OUTLINE (D)	PLASTIC DUAL-IN-LINE (P)				
0°C to 70°C	TL3472CD	TL3472CP				
-40°C to 105°C	TL3472ID	TL3472IP				

AVAILABLE OPTIONS

D package is available taped and reeled. Add the suffix R to device type (e.g., TL3472CDR).



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage (see Note 1): V _{CC+}	
V _{CC}	18 V
Differential input voltage, V _{ID} (see Note 2)	±36 V
Input voltage, V _I (any input)	V _{CC±}
Input current, I _I (each input)	±1 mA
Output current, I _O	±80 mA
Total current into V _{CC+}	80 mA
Total current out of V _{CC}	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	Unlimited
Package thermal impedance, θ_{JA} (see Notes 4 and 5): D package	97°C/W
P package	85°C/W
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between VCC+ and VCC-.
 - 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive input current can flow when the input is less than V_{CC} 0.3 V.

3. The output can be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

- 4. Maximum power dissipation is a function of T_J(max), θ_{JA} , and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/ θ_{JA} . Operating at the absolute maximum T_J of 150°C can impact reliability.
- 5. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions

			MIN	MAX	UNIT
V _{CC±}	V _{CC±} Supply voltage			36	V
VIC Co	Common-mode input voltage	$V_{CC} = 5 V$	0	2.8	v
		$V_{CC\pm} = \pm 15 \text{ V}$	-15	12.8	
т _А	Operating free-air temperature	TL3472C	0	70	°C
		TL3472I	-40	105	Ŭ



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	PARAMETER	TEST CONDITIONS		ТА	MIN	TYP [†]	MAX	UNIT
			V _{CC} = 5 V	25°C		1.5	10	
V _{IO} Input	Input offset voltage			25°C		1.0	10	mV
		V _{CC} = ±15 V		Full range‡			12	
$\alpha_{V_{IO}}$	Temperature coefficient of input offset voltage	$V_{IC} = 0,$ $V_{O} = 0,$	$V_{CC} = \pm 15 V$	Full range‡		10		μV/° (
l. a	Input offset current	R _S = 50 Ω	25°C		6	75	-	
10	input onset current		$V_{CC} = \pm 15 V$	Full range‡			300	nA
lun.	Input bias current		V _{CC} = ±15 V	25°C		100	500	μA
IΒ	Input bias current	VCC = ±15 V	Full range‡			700	μΑ	
VICR Common-mode input voltage range	Common-mode	R _S = 50 Ω		25°C		-15 to 12.8		V
	input voltage range			Full range‡		-15 to 12.8		V
		V _{CC+} = 5 V,	$V_{CC-} = 0$, $R_L = 2 k\Omega$	25°C	3.7	4		
Vон	High-level output voltage	$R_L = 10 \ k\Omega$		25°C	13.6	14		V
		$R_L = 2 k\Omega$		Full range‡	13.4			
		V _{CC+} = 5 V,	$V_{CC-} = 0$, $R_L = 2 k\Omega$	25°C		0.1	0.3	
Vol	Low-level output voltage	$R_L = 10 \ k\Omega$		25°C		-14.7	-14.3	V
		$R_L = 2 k\Omega$		Full range‡			-13.5	
A. (5)	Large-signal differential voltage amplification	$V_{\Omega} = \pm 10 \text{ V}, \qquad R_{I} = 2 \text{ k}\Omega$	$R_{I} = 2 k\Omega$	25°C	25	100		V/m
AVD		$V_{O} = \pm 10 V$, $K_{L} = 2 K_{S2}$		Full range‡	20			V/IIIV
	Short-circuit output current	Source: V _{ID} = 1 V,	urce: $V_{ID} = 1 V$, $V_O = 0$		-10	-34		
los		Sink: $V_{ID} = -1 V$,	$V_{O} = 0$	25°C	20	27		mA
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}(min),$	R _S = 50 Ω	25°C	65	97		dB
^k svr	Supply-voltage rejection ratio $(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC\pm} = \pm 13.5 \text{ V to}$	±16.5 V, R _S = 100 Ω	25°C	70	97		dB
	Supply current (per channel)	V _O = 0, No load	No load	25°C		3.5	4.5	
ICC				Full range‡		4.5	5.5	mA
		$V_{CC+} = 5 V, V_{O} = 2$	2.5 V, V _{CC} _ = 0, No load	25°C		3.5	4.5	

[†] All typical values are at $T_A = 25^{\circ}C$. [‡] Full range is 0°C to 70°C for the TL3472C device and -40°C to 105°C for the TL3472I device.



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operating characteristics, V_{CC\pm} = ± 15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR+	Positive slew rate	$V_{I} = -10 V$ to 10 V,	A _V = 1	8	10		V/µs
SR-	Negative slew rate	$R_L = 2 \text{ k}\Omega$, $C_L = 300 \text{ pF}$	$A_V = -1$		13		V/µs
t _s	Settling time	A _{VD} = -1, 10-V step	To 0.1%		1.1		
			To 0.01%		2.2		μs
Vn	Equivalent input noise voltage	f = 1 kHz,	R _S = 100 Ω		49		nV/√Hz
In	Equivalent input noise current	f = 1 kHz		0.22		pA/√Hz	
THD	Total harmonic distortion	$V_{O(PP)} = 2 V \text{ to } 20 V, R_{L} = 2 k\Omega, A_{VD} = 10, f = 10 \text{ kHz}$			0.02		%
GBW	Gain-bandwidth product	f =100 kHz		3	4		MHz
BW	Power bandwidth	$V_{O(PP)} = 20 \text{ V}, \text{ R}_{L} = 2 \text{ k}\Omega, \text{ A}_{VD} = 1, \text{ THD} = 5.0\%$			160		kHz
	Phase margin	$R_L = 2 k\Omega$	$C_L = 0$		70		den
φm			C _L = 300 pF		50		deg
	Gain margin	P ako	CL = 0		12		dB
		$R_{L} = 2 k\Omega$	C _L = 300 pF		4		
rj	Differential input resistance	$V_{IC} = 0$			150		MΩ
Ci	Input capacitance	$V_{IC} = 0$			2.5		pF
	Channel separation	f = 10 kHz			101		dB
z ₀	Open-loop output impedance	f = 1 MHz,	A _V = 1		20		Ω



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